



TABLE 1. PIN DESCRIPTIONS

| Number | Name              | Type   |          | Description                                                                                                                                                             |
|--------|-------------------|--------|----------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1, 2   | V <sub>CCO</sub>  | Power  |          | Output supply pins.                                                                                                                                                     |
| 3, 4   | nQ2, Q2           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |
| 5, 6   | nQ1, Q1           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |
| 7, 8   | nQ0, Q0           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |
| 9      | PLL_BYPASS        | Input  | Pullup   | Selects between the PLL and crystal inputs as the input to the dividers. When LOW, selects PLL. When HIGH, selects XTAL_IN, XTAL_OUT. LVCMOS / LVTTTL interface levels. |
| 10     | V <sub>CCA</sub>  | Power  |          | Analog supply pin.                                                                                                                                                      |
| 11     | V <sub>CC</sub>   | Power  |          | Core supply pin.                                                                                                                                                        |
| 12     | FB_SEL            | Input  | Pulldown | Feedback frequency select pin. LVCMOS/LVTTTL interface levels.                                                                                                          |
| 13, 14 | XTAL_IN, XTAL_OUT | Input  |          | Crystal oscillator interface. XTAL_IN is the input. XTAL_OUT is the output.                                                                                             |
| 15, 18 | N_SEL0<br>N_SEL1  | Input  | Pullup   | Output frequency select pin. LVCMOS/LVTTTL interface levels.                                                                                                            |
| 16, 17 | V <sub>EE</sub>   |        |          | Negative supply pin.                                                                                                                                                    |
| 19, 20 | nQ5, Q5           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |
| 21, 22 | nQ4, Q4           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |
| 23, 24 | nQ3, Q3           | Output |          | Differential output pair. LVPECL interface levels.                                                                                                                      |

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

| Symbol                | Parameter               | Test Conditions | Minimum | Typical | Maximum | Units |
|-----------------------|-------------------------|-----------------|---------|---------|---------|-------|
| C <sub>IN</sub>       | Input Capacitance       |                 |         | 4       |         | pF    |
| R <sub>PULLDOWN</sub> | Input Pulldown Resistor |                 |         | 51      |         | kΩ    |
| R <sub>PULLUP</sub>   | Input Pullup Resistor   |                 |         | 51      |         | kΩ    |

TABLE 3. CRYSTAL FUNCTION TABLE

| Inputs     |        |        |        | Function |           |   |              |
|------------|--------|--------|--------|----------|-----------|---|--------------|
| XTAL (MHz) | FB_SEL | N_SEL1 | N_SEL0 | M        | VCO (MHz) | N | Output (MHz) |
| 20         | 0      | 0      | 0      | 25       | 500       | 1 | 500          |
| 20         | 0      | 0      | 1      | 25       | 500       | 2 | 250          |
| 20         | 0      | 1      | 0      | 25       | 500       | 4 | 125          |
| 20         | 0      | 1      | 1      | 25       | 500       | 5 | 100          |
| 21.25      | 0      | 1      | 1      | 25       | 531.25    | 5 | 106.25       |
| 24         | 0      | 0      | 0      | 25       | 600       | 1 | 600          |
| 24         | 0      | 0      | 1      | 25       | 600       | 2 | 300          |
| 24         | 0      | 1      | 0      | 25       | 600       | 4 | 150          |
| 24         | 0      | 1      | 1      | 25       | 600       | 5 | 120          |
| 25         | 0      | 0      | 0      | 25       | 625       | 1 | 625          |
| 25         | 0      | 0      | 1      | 25       | 625       | 2 | 312.5        |
| 25         | 0      | 1      | 0      | 25       | 625       | 4 | 156.25       |
| 25         | 0      | 1      | 1      | 25       | 625       | 5 | 125          |
| 25.5       | 0      | 1      | 0      | 25       | 637.5     | 4 | 159.375      |
| 15.625     | 1      | 1      | 1      | 32       | 500       | 8 | 62.5         |
| 18.5625    | 1      | 1      | 1      | 32       | 594       | 8 | 74.25        |
| 18.75      | 1      | 0      | 0      | 32       | 600       | 1 | 600          |
| 18.75      | 1      | 0      | 1      | 32       | 600       | 2 | 300          |
| 18.75      | 1      | 1      | 0      | 32       | 600       | 4 | 150          |
| 18.75      | 1      | 1      | 1      | 32       | 600       | 8 | 75           |
| 19.44      | 1      | 0      | 0      | 32       | 622.08    | 1 | 622.08       |
| 19.44      | 1      | 0      | 1      | 32       | 622.08    | 2 | 311.04       |
| 19.44      | 1      | 1      | 0      | 32       | 622.08    | 4 | 155.52       |
| 19.44      | 1      | 1      | 1      | 32       | 622.08    | 8 | 77.76        |
| 19.53125   | 1      | 0      | 0      | 32       | 625       | 1 | 625          |
| 19.53125   | 1      | 0      | 1      | 32       | 625       | 2 | 312.5        |
| 19.53125   | 1      | 1      | 0      | 32       | 625       | 4 | 156.25       |
| 19.53125   | 1      | 1      | 1      | 32       | 625       | 8 | 78.125       |
| 20         | 1      | 1      | 1      | 32       | 640       | 8 | 80           |

## ABSOLUTE MAXIMUM RATINGS

|                                          |                          |
|------------------------------------------|--------------------------|
| Supply Voltage, $V_{CC}$                 | 4.6V                     |
| Inputs, $V_I$                            | -0.5V to $V_{CC} + 0.5V$ |
| Outputs, $I_O$                           |                          |
| Continuous Current                       | 50mA                     |
| Surge Current                            | 100mA                    |
| Package Thermal Impedance, $\theta_{JA}$ | 37°C/W (0 mps)           |
| Storage Temperature, $T_{STG}$           | -65°C to 150°C           |

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 4A. POWER SUPPLY DC CHARACTERISTICS,  $V_{CC} = V_{CCO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

| Symbol    | Parameter             | Test Conditions | Minimum         | Typical | Maximum | Units |
|-----------|-----------------------|-----------------|-----------------|---------|---------|-------|
| $V_{CC}$  | Core Supply Voltage   |                 | 3.135           | 3.3     | 3.465   | V     |
| $V_{CCA}$ | Analog Supply Voltage |                 | $V_{CC} - 0.12$ | 3.3     | 3.465   | V     |
| $V_{CCO}$ | Output Supply Voltage |                 | 3.135           | 3.3     | 3.465   | V     |
| $I_{EE}$  | Power Supply Current  |                 |                 |         | 190     | mA    |
| $I_{CCA}$ | Analog Supply Current |                 |                 |         | 12      | mA    |

TABLE 4B. POWER SUPPLY DC CHARACTERISTICS,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{CCO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

| Symbol    | Parameter             | Test Conditions | Minimum         | Typical | Maximum | Units |
|-----------|-----------------------|-----------------|-----------------|---------|---------|-------|
| $V_{CC}$  | Core Supply Voltage   |                 | 3.135           | 3.3     | 3.465   | V     |
| $V_{CCA}$ | Analog Supply Voltage |                 | $V_{CC} - 0.12$ | 3.3     | 3.465   | V     |
| $V_{CCO}$ | Output Supply Voltage |                 | 2.375           | 2.5     | 2.625   | V     |
| $I_{EE}$  | Power Supply Current  |                 |                 |         | 190     | mA    |
| $I_{CCA}$ | Analog Supply Current |                 |                 |         | 12      | mA    |

TABLE 4C. LVCMOS / LVTTTL DC CHARACTERISTICS,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{CCO} = 3.3V \pm 5\%$  OR  $2.5V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

| Symbol   | Parameter          | Test Conditions                                                 | Minimum | Typical | Maximum        | Units   |
|----------|--------------------|-----------------------------------------------------------------|---------|---------|----------------|---------|
| $V_{IH}$ | Input High Voltage |                                                                 | 2       |         | $V_{CC} + 0.3$ | V       |
| $V_{IL}$ | Input Low Voltage  |                                                                 | -0.3    |         | 0.8            | V       |
| $I_{IH}$ | Input High Current | FB_SEL<br>$V_{CC} = V_{IN} = 3.465V$                            |         |         | 150            | $\mu A$ |
|          |                    | PLL_BYPASS,<br>N_SEL0, N_SEL1<br>$V_{CC} = V_{IN} = 3.465V$     |         |         | 5              | $\mu A$ |
| $I_{IL}$ | Input Low Current  | FB_SEL<br>$V_{CC} = 3.465V, V_{IN} = 0V$                        | -5      |         |                | $\mu A$ |
|          |                    | PLL_BYPASS,<br>N_SEL0, N_SEL1<br>$V_{CC} = 3.465V, V_{IN} = 0V$ | -150    |         |                | $\mu A$ |

**TABLE 4D. LVPECL DC CHARACTERISTICS**,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{CCO} = 3.3V \pm 5\%$  OR  $2.5V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

| Symbol      | Parameter                         | Test Conditions | Minimum         | Typical | Maximum         | Units |
|-------------|-----------------------------------|-----------------|-----------------|---------|-----------------|-------|
| $V_{OH}$    | Output High Voltage; NOTE 1       |                 | $V_{CCO} - 1.4$ |         | $V_{CCO} - 0.9$ | V     |
| $V_{OL}$    | Output Low Voltage; NOTE 1        |                 | $V_{CCO} - 2.0$ |         | $V_{CCO} - 1.7$ | V     |
| $V_{SWING}$ | Peak-to-Peak Output Voltage Swing |                 | 0.6             |         | 1.0             | V     |

NOTE 1: Outputs terminated with  $50\Omega$  to  $V_{CCO} - 2V$ .**TABLE 5. CRYSTAL CHARACTERISTICS**

| Parameter                          | Test Conditions | Minimum     | Typical | Maximum | Units    |
|------------------------------------|-----------------|-------------|---------|---------|----------|
| Mode of Oscillation                |                 | Fundamental |         |         |          |
| Frequency                          |                 | 15.625      |         | 25.5    | MHz      |
| Equivalent Series Resistance (ESR) |                 |             |         | 50      | $\Omega$ |
| Shunt Capacitance                  |                 |             |         | 7       | pF       |
| Drive Level                        |                 |             |         | 1       | mW       |

NOTE: Characterized using an 18pF parallel resonant crystal.

**TABLE 6A. AC CHARACTERISTICS**,  $V_{CC} = V_{CCO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

| Symbol               | Parameter                 | Test Conditions                                   | Minimum | Typical | Maximum | Units |
|----------------------|---------------------------|---------------------------------------------------|---------|---------|---------|-------|
| $F_{OUT}$            | Output Frequency          |                                                   | 62.5    |         | 625     | MHz   |
| $t_{jit}(\emptyset)$ | RMS Phase Jitter (Random) | 156.25MHz, Integration Range:<br>1.875MHz - 20MHz |         | 0.41    |         | ps    |
|                      |                           | 156.25MHz, Integration Range:<br>12kHz - 20MHz    |         | 0.85    |         | ps    |
| $t_{sk(o)}$          | Output Skew; NOTE 1, 2    |                                                   |         |         | 40      | ps    |
| $t_R / t_F$          | Output Rise/Fall Time     | 20% to 80%                                        | 200     |         | 650     | ps    |
| odc                  | Output Duty Cycle         | $F_{OUT} \leq 312.5\text{MHz}$                    | 47      |         | 53      | %     |
|                      |                           | $F_{OUT} > 312.5\text{MHz}$                       | 45      |         | 55      | %     |
| $t_{LOCK}$           | PLL Lock Time             |                                                   |         |         | 20      | ms    |

See Parameter Measurement Information section.

NOTE 1: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the output differential crossing points.

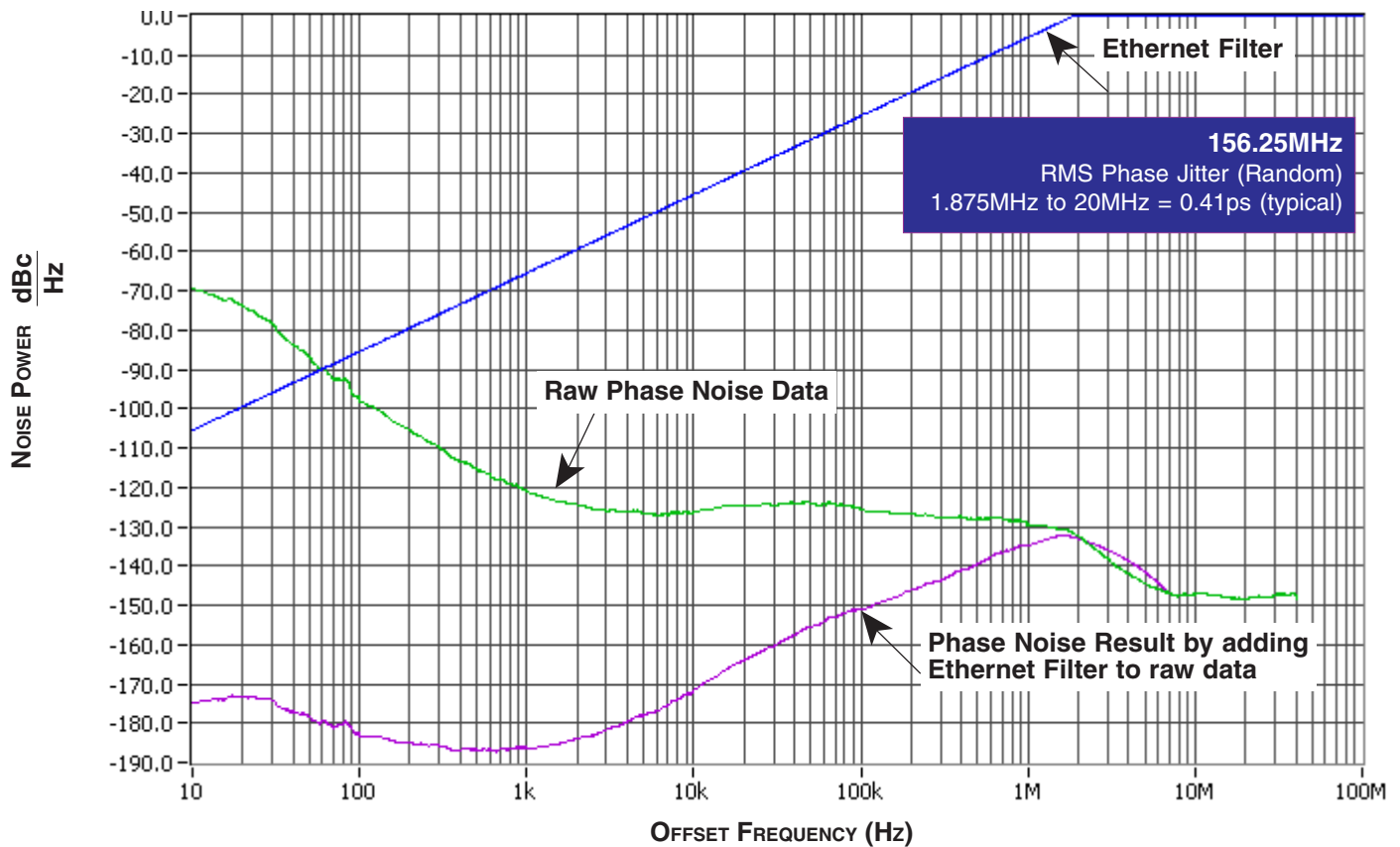
NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.

**TABLE 6B. AC CHARACTERISTICS**,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{CCO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ\text{C}$  TO  $70^\circ\text{C}$ 

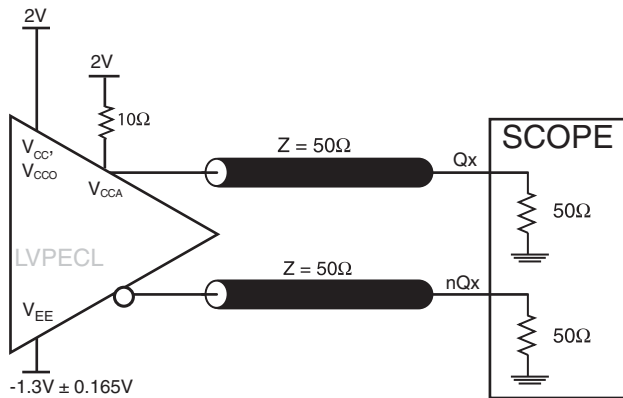
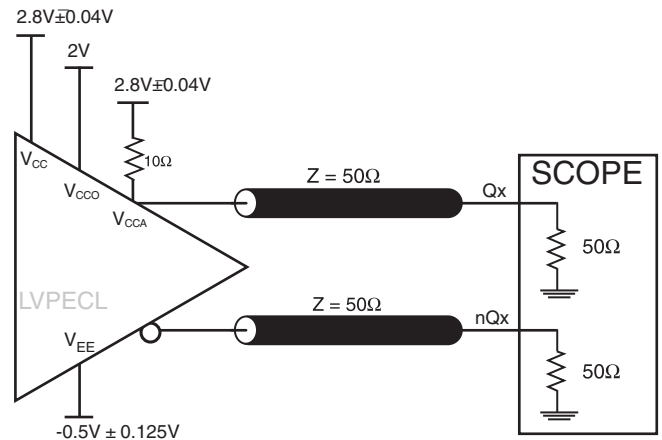
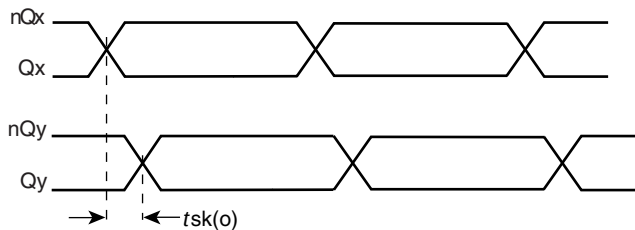
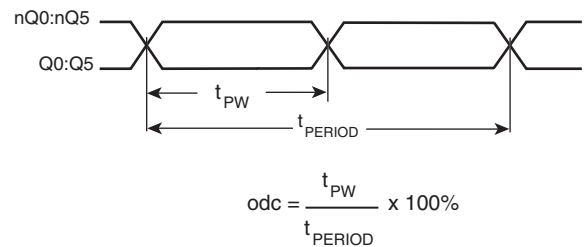
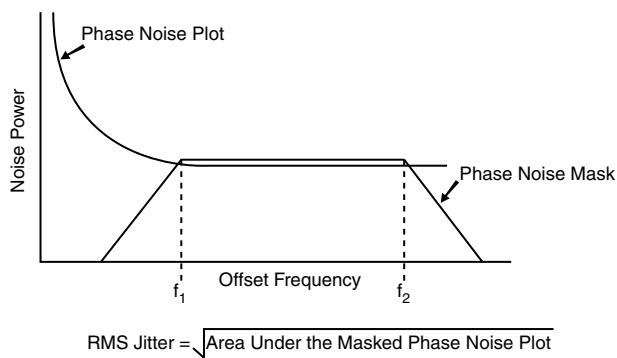
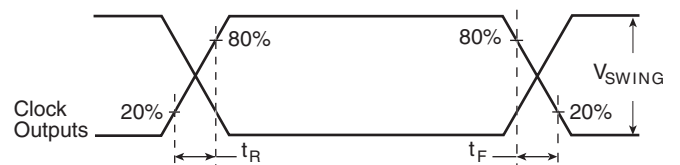
| Symbol               | Parameter                 | Test Conditions                                   | Minimum | Typical | Maximum | Units |
|----------------------|---------------------------|---------------------------------------------------|---------|---------|---------|-------|
| $F_{OUT}$            | Output Frequency          |                                                   | 62.5    |         | 625     | MHz   |
| $t_{jit}(\emptyset)$ | RMS Phase Jitter (Random) | 156.25MHz, Integration Range:<br>1.875MHz - 20MHz |         | 0.41    |         | ps    |
|                      |                           | 156.25MHz, Integration Range:<br>12kHz - 20MHz    |         | 0.85    |         | ps    |
| $t_{sk(o)}$          | Output Skew; NOTE 1, 2    |                                                   |         |         | 45      | ps    |
| $t_R / t_F$          | Output Rise/Fall Time     | 20% to 80%                                        | 200     |         | 650     | ps    |
| odc                  | Output Duty Cycle         |                                                   | 46      |         | 54      | %     |
| $t_{LOCK}$           | PLL Lock Time             |                                                   |         |         | 20      | ms    |

For NOTES, please see Table 6A above.

## TYPICAL PHASE NOISE AT 156.25MHz @ 3.3V



## PARAMETER MEASUREMENT INFORMATION


**3.3V CORE/3.3V OUTPUT LOAD AC TEST CIRCUIT**

**3.3V CORE/2.5V OUTPUT LOAD AC TEST CIRCUIT**

**OUTPUT SKEW**

**OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD**

**RMS PHASE JITTER**

**OUTPUT RISE/FALL TIME**

## APPLICATION INFORMATION

### POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS843256 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{CC}$ ,  $V_{CCA}$ , and  $V_{CCO}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a  $10\Omega$  resistor along with a  $10\mu F$  and a  $.01\mu F$  bypass capacitor should be connected to each  $V_{CCA}$  pin.

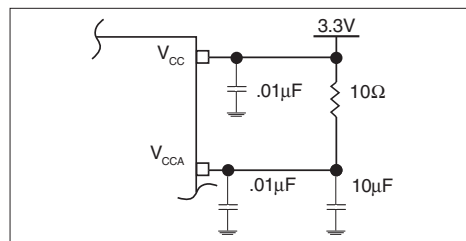


FIGURE 1. POWER SUPPLY FILTERING

### RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

#### INPUTS:

##### LVC MOS CONTROL PINS

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1k\Omega$  resistor can be used.

#### OUTPUTS:

##### LVPECL OUTPUTS

All unused LVPECL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

### CRYSTAL INPUT INTERFACE

The ICS843256 has been characterized with  $18pF$  parallel resonant crystals. The capacitor values shown in *Figure 2* below

were determined using an  $18pF$  parallel resonant crystal and were chosen to minimize the ppm error.

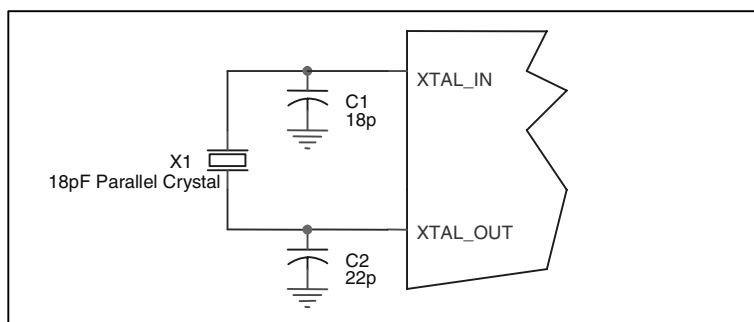


FIGURE 2. CRYSTAL INPUT INTERFACE

## LVC MOS TO XTAL INTERFACE

The XTAL\_IN input can accept a single-ended LVC MOS signal through an AC coupling capacitor. A general interface diagram is shown in *Figure 3*. The XTAL\_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVC MOS inputs, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output

impedance of the driver ( $R_o$ ) plus the series resistance ( $R_s$ ) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First,  $R1$  and  $R2$  in parallel should equal the transmission line impedance. For most  $50\Omega$  applications,  $R1$  and  $R2$  can be  $100\Omega$ . This can also be accomplished by removing  $R1$  and making  $R2$   $50\Omega$ .

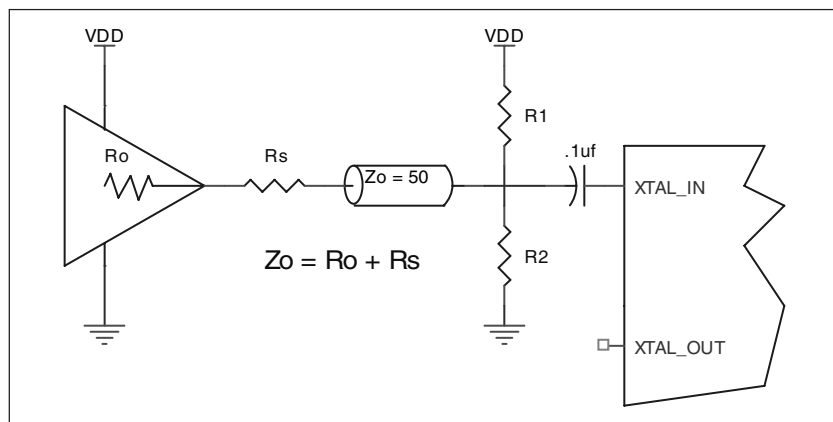


FIGURE 3. GENERAL DIAGRAM FOR LVC MOS DRIVER TO XTAL INPUT INTERFACE

## TERMINATION FOR LVPECL OUTPUTS

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

FOUT and nFOUT are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive  $50\Omega$

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 4A and 4B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

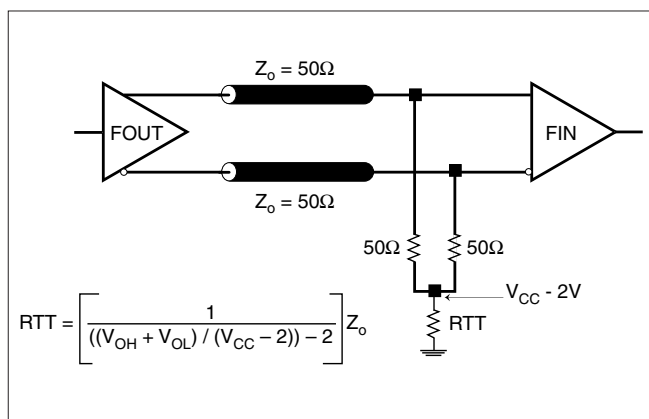


FIGURE 4A. LVPECL OUTPUT TERMINATION

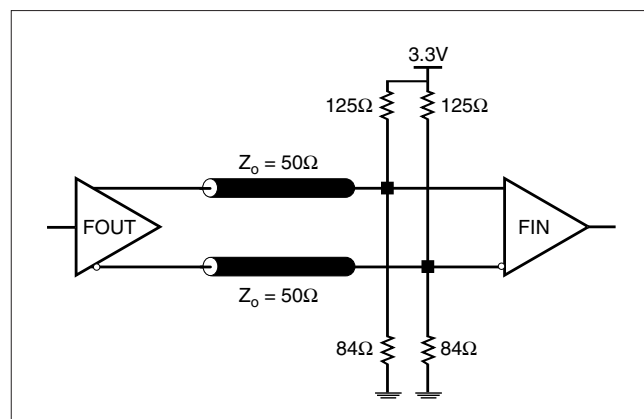


FIGURE 4B. LVPECL OUTPUT TERMINATION

### TERMINATION FOR 2.5V LVPECL OUTPUT

Figure 5A and Figure 5B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating  $50\Omega$  to  $V_{cc} - 2V$ . For  $V_{cc} = 2.5V$ , the  $V_{cc} - 2V$  is very close to

ground level. The  $R3$  in Figure 5B can be eliminated and the termination is shown in Figure 5C.

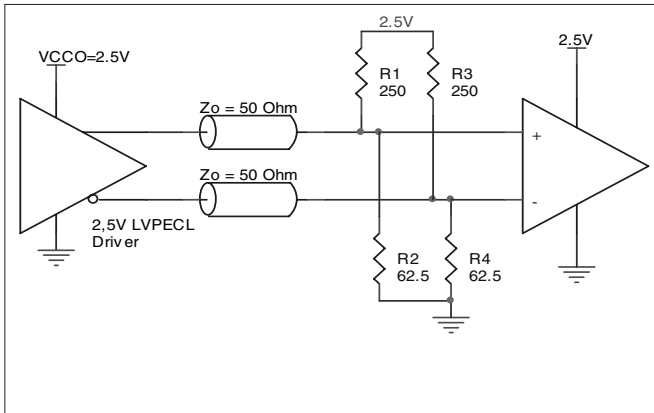


FIGURE 5A. 2.5V LVPECL DRIVER TERMINATION EXAMPLE

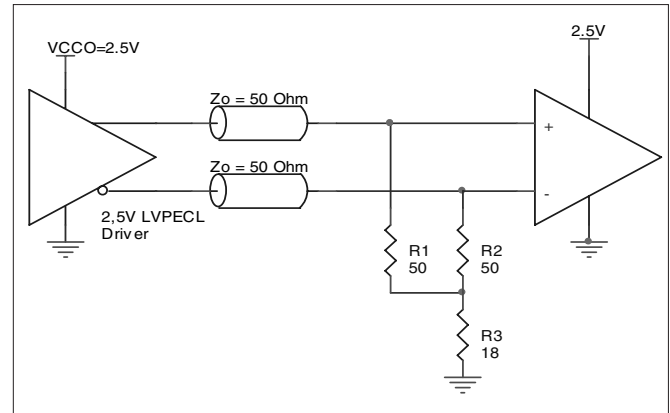


FIGURE 5B. 2.5V LVPECL DRIVER TERMINATION EXAMPLE

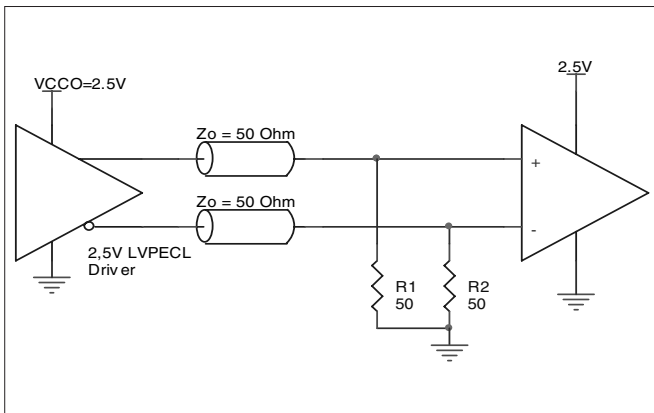


FIGURE 5C. 2.5V LVPECL TERMINATION EXAMPLE

## POWER CONSIDERATIONS

This section provides information on power dissipation and junction temperature for the ICS843256. Equations and example calculations are also provided.

### 1. Power Dissipation.

The total power dissipation for the ICS843256 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for  $V_{CC} = 3.3V + 5\% = 3.465V$ , which gives worst case results.

**NOTE:** Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)<sub>MAX</sub> =  $V_{CC\_MAX} * I_{EE\_MAX} = 3.465V * 190mA = 658.35mW$
- Power (outputs)<sub>MAX</sub> = **30mW/Loaded Output pair**  
If all outputs are loaded, the total power is  $6 * 30mW = 180mW$

$$\text{Total Power}_{MAX} (3.465V, \text{ with all outputs switching}) = 658.35mW + 180mW = 838.35mW$$

### 2. Junction Temperature.

Junction temperature,  $T_j$ , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS™ devices is 125°C.

The equation for  $T_j$  is as follows:  $T_j = \theta_{JA} * Pd\_total + T_A$

$T_j$  = Junction Temperature

$\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

$Pd\_total$  = Total Device Power Dissipation (example calculation is in section 1 above)

$T_A$  = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 37°C/W per Table 7 below.

Therefore,  $T_j$  for an ambient temperature of 70°C with all outputs switching is:

$$70^\circ C + 0.838W * 37^\circ C/W = 101^\circ C. \text{ This is well below the limit of } 125^\circ C.$$

This calculation is only an example.  $T_j$  will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

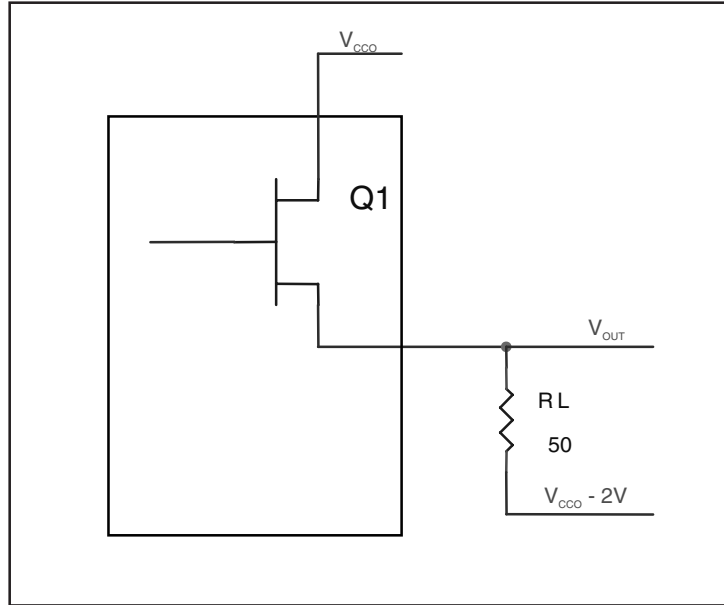
**TABLE 7B. THERMAL RESISTANCE  $\theta_{JA}$  FOR 24-PIN TSSOP, E-PAD FORCED CONVECTION**

|                                             | $\theta_{JA}$ by Velocity (Meters per Second) |        |        |
|---------------------------------------------|-----------------------------------------------|--------|--------|
|                                             | 0                                             | 1      | 2.5    |
| Multi-Layer PCB, JEDEC Standard Test Boards | 37°C/W                                        | 31°C/W | 30°C/W |

### 3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in *Figure 6*.



**FIGURE 6. LVPECL DRIVER CIRCUIT AND TERMINATION**

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of  $V_{CCO} - 2V$ .

- For logic high,  $V_{OUT} = V_{OH\_MAX} = V_{CCO\_MAX} - 0.9V$

$$(V_{CCO\_MAX} - V_{OH\_MAX}) = 0.9V$$

- For logic low,  $V_{OUT} = V_{OL\_MAX} = V_{CCO\_MAX} - 1.7V$

$$(V_{CCO\_MAX} - V_{OL\_MAX}) = 1.7V$$

$Pd\_H$  is power dissipation when the output drives high.

$Pd\_L$  is the power dissipation when the output drives low.

$$Pd\_H = [(V_{OH\_MAX} - (V_{CCO\_MAX} - 2V))/R_L] * (V_{CCO\_MAX} - V_{OH\_MAX}) = [(2V - (V_{CCO\_MAX} - V_{OH\_MAX}))/R_L] * (V_{CCO\_MAX} - V_{OH\_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = 19.8mW$$

$$Pd\_L = [(V_{OL\_MAX} - (V_{CCO\_MAX} - 2V))/R_L] * (V_{CCO\_MAX} - V_{OL\_MAX}) = [(2V - (V_{CCO\_MAX} - V_{OL\_MAX}))/R_L] * (V_{CCO\_MAX} - V_{OL\_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = 10.2mW$$

$$\text{Total Power Dissipation per output pair} = Pd\_H + Pd\_L = 30mW$$

RELIABILITY INFORMATION

TABLE 8.  $\theta_{JA}$  VS. AIR FLOW TABLE FOR 24 LEAD TSSOP, E-PAD

| $\theta_{JA}$ by Velocity (Meters per Second) |        |        |        |
|-----------------------------------------------|--------|--------|--------|
|                                               | 0      | 1      | 2.5    |
| Multi-Layer PCB, JEDEC Standard Test Boards   | 37°C/W | 31°C/W | 30°C/W |

TRANSISTOR COUNT

The transistor count for ICS843256 is: 3863

## PACKAGE OUTLINE - G SUFFIX FOR 24 LEAD TSSOP, E-PAD

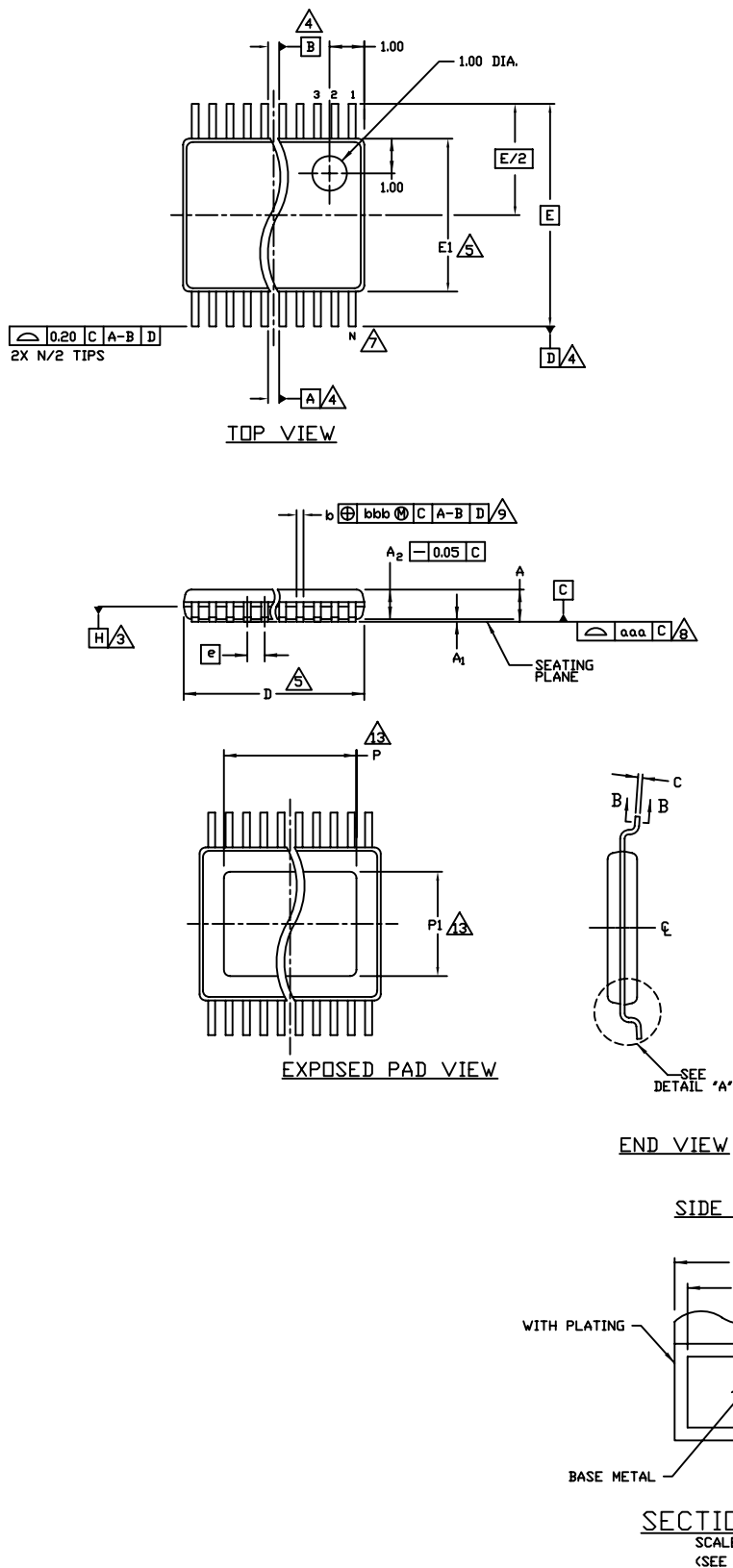


TABLE 9. PACKAGE DIMENSIONS

| SYMBOL   | Millimeters |         |         |
|----------|-------------|---------|---------|
|          | Minimum     | Nominal | Maximum |
| N        | 24          |         |         |
| A        | --          |         | 1.10    |
| A1       | 0.05        |         | 0.15    |
| A2       | 0.85        | 0.90    | 0.95    |
| b        | 0.19        |         | 0.30    |
| b1       | 0.19        | 0.22    | 0.25    |
| c        | 0.09        |         | 0.20    |
| c1       | 0.09        | 0.127   | 0.16    |
| D        | 7.70        | 7.80    | 7.90    |
| E        | 6.40 BASIC  |         |         |
| E1       | 4.30        | 4.40    | 4.50    |
| e        | 0.65 BASIC  |         |         |
| L        | 0.50        | 0.60    | 0.70    |
| P        |             |         | 5.0     |
| P1       |             |         | 3.2     |
| $\alpha$ | 0°          |         | 8°      |
| aaa      | 0.076       |         |         |
| bbb      | 0.10        |         |         |

Reference Document: JEDEC Publication 95, MO-153

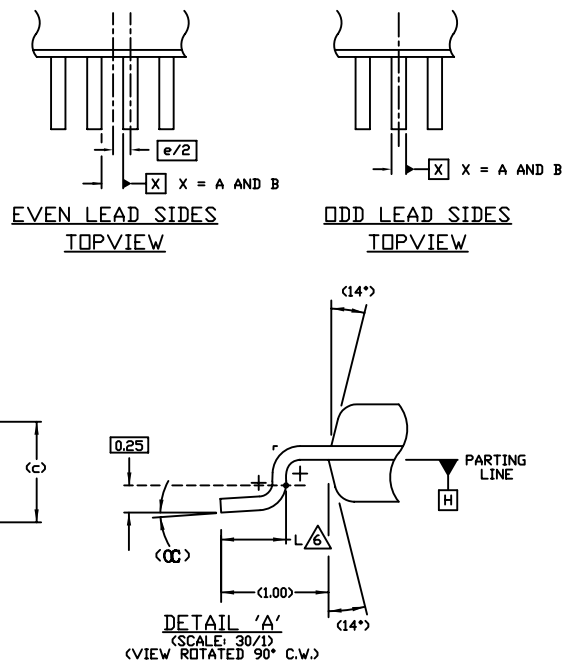


TABLE 10. ORDERING INFORMATION

| Part/Order Number | Marking       | Package                          | Shipping Packaging | Temperature |
|-------------------|---------------|----------------------------------|--------------------|-------------|
| ICS843256BG       | ICS843256BG   | 24 Lead TSSOP, E-Pad             | tube               | 0°C to 70°C |
| ICS843256BGT      | ICS843256BG   | 24 Lead TSSOP, E-Pad             | 2500 tape & reel   | 0°C to 70°C |
| ICS843256BGLF     | ICS843256BGLF | 24 Lead "Lead-Free" TSSOP, E-Pad | tube               | 0°C to 70°C |
| ICS843256BGLFT    | ICS843256BGLF | 24 Lead "Lead-Free" TSSOP, E-Pad | 2500 tape & reel   | 0°C to 70°C |

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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